Product data sheet

Product profile 1.

1.1 General description

Enhanced ultrafast power diode in a SOT428 (DPAK) plastic package.

1.2 Features and benefits

- High thermal cycling performance
- Low on-state losses
- Low thermal resistance

- Soft recovery characteristic
- Surface-mountable package

1.3 Applications

■ Dual Mode (DCM and CCM) PFC

■ Power Factor Correction (PFC) for Interleaved Topology

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{F(AV)}	average forward current	square-wave pulse; $\delta = 0.5$; $T_{mb} \le 121$ °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	5	Α
Static char	acteristics					
V_{F}	forward voltage	$I_F = 5 \text{ A}; T_j = 25 \text{ °C};$ see Figure 5	-	1.3	1.9	V
		$I_F = 5 \text{ A}$; $T_j = 150 \text{ °C}$; see Figure 5	-	1.1	1.7	V
Dynamic c	haracteristics					
t _{rr}	reverse recovery time	$I_F = 1 \text{ A; } V_R = 30 \text{ V;}$ $dI_F/dt = 100 \text{ A/}\mu\text{s; } T_j = 25 \text{ °C;}$ see Figure 6	-	17.5	35	ns



Pinning information

Table 2. **Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		v 14 .
2	K	cathode[1]	mb	K — A 001aaa020
3	Α	anode		
mb	K	mounting base; cathode	1 3	
			SOT428 (DPAK)	

^[1] It is not possible to connect to pin 2 of the SOT428 package.

Ordering information

Table 3. **Ordering information**

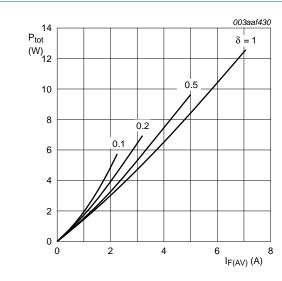
Type number	Package		
	Name	Description	Version
BYV25FD-600	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428

Limiting values

Table 4. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

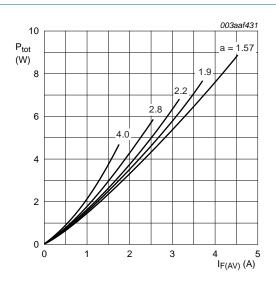
Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	600	V
V_{RWM}	crest working reverse voltage		-	600	V
V_R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	square-wave pulse; δ = 0.5; $T_{mb} \le$ 121 °C; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	5	A
I _{FRM}	repetitive peak forward current	square-wave pulse; δ = 0.5 ; t_p = 25 μ s; $T_{mb} \le$ 121 °C	-	10	Α
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; see <u>Figure 3</u>	-	60	Α
		t_p = 8.3 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; see <u>Figure 3</u>	-	66	Α
T _{stg}	storage temperature		-40	150	°C
T _i	junction temperature		-	150	°C



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

 $V_0 = 1.499 \text{ V}; R_s = 0.041 \Omega$

Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



 $a = \text{form factor} = I_{F(RMS)} / I_{F(AV)}$

 $V_o = 1.499 \text{ V}; R_s = 0.041 \Omega$

Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

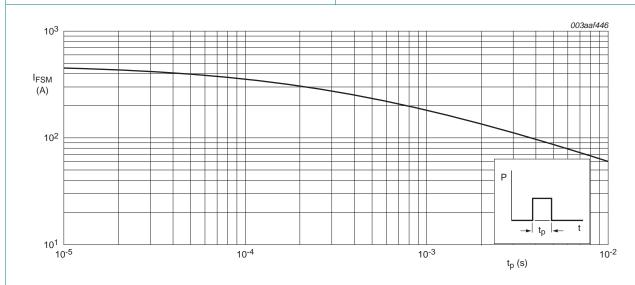


Fig 3. Non-repetitive peak forward current as a function of pulse width; square waveform; maximum values

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	see Figure 4	-	-	3	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1] -	50	-	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

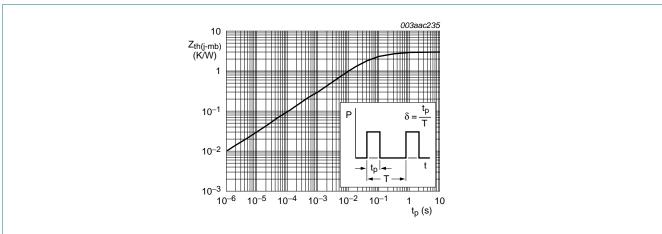
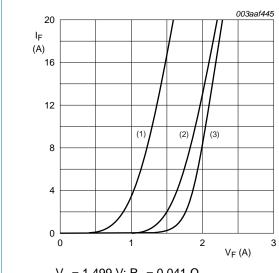


Fig 4. Transient thermal impedance from junction to mounting base as a function of pulse width

Characteristics

Table 6. **Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	Static characteristics					
V _F	forward voltage	$I_F = 5 \text{ A}$; $T_j = 25 \text{ °C}$; see Figure 5	-	1.3	1.9	V
		I _F = 5 A; T _j = 150 °C; see <u>Figure 5</u>	-	1.1	1.7	V
I _R	reverse current	V _R = 600 V; T _j = 100 °C	-	-	1.5	mA
		V _R = 600 V; T _j = 25 °C	-	-	50	μΑ
Dynamic ch	Dynamic characteristics					
Q _r	recovered charge	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; see Figure 6	-	13	-	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; see Figure 6	-	17.5	35	ns
I _{RM}	peak reverse recovery current	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; see Figure 6	-	1.5	-	Α
V_{FRM}	forward recovery voltage	$I_F = 1 \text{ A}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; see Figure 7	-	3.2	-	V



 $V_o = 1.499 \text{ V}; R_s = 0.041 \Omega$

(1) T_j = 150 °C; typical values;

(2) T_i = 150 °C; maximum values;

(3) $T_j = 25$ °C; maximum values;

Fig 5. Forward current as a function of forward voltage

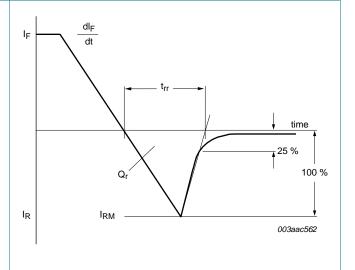
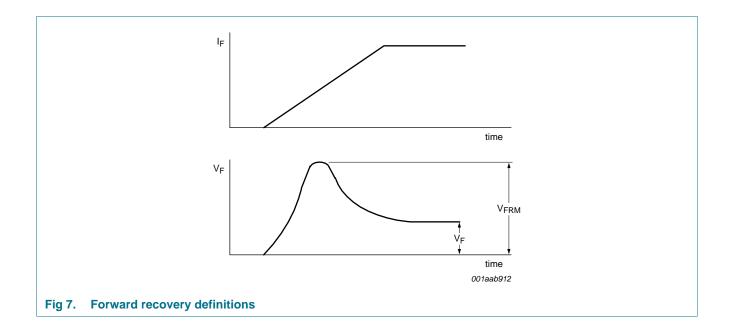


Fig 6. Reverse recovery definitions; ramp recovery



7. Package outline

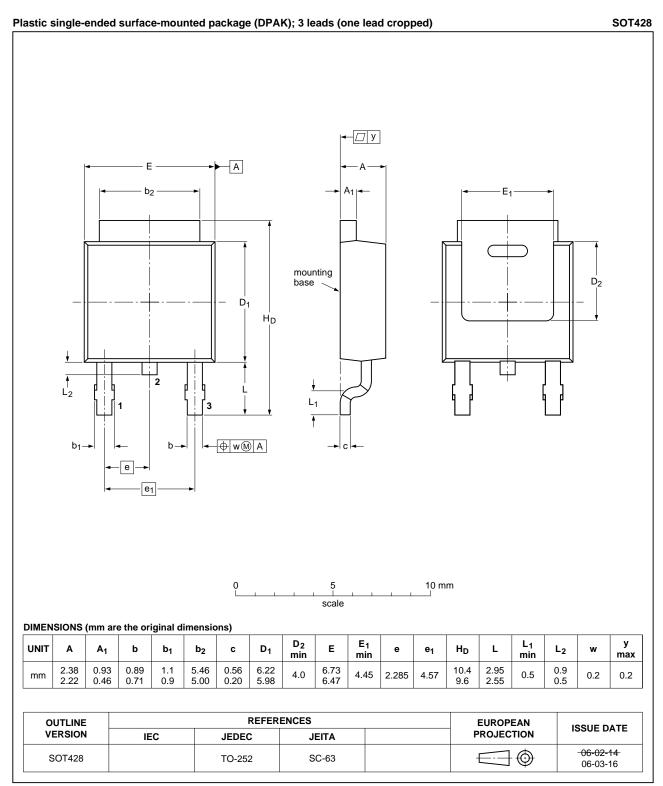
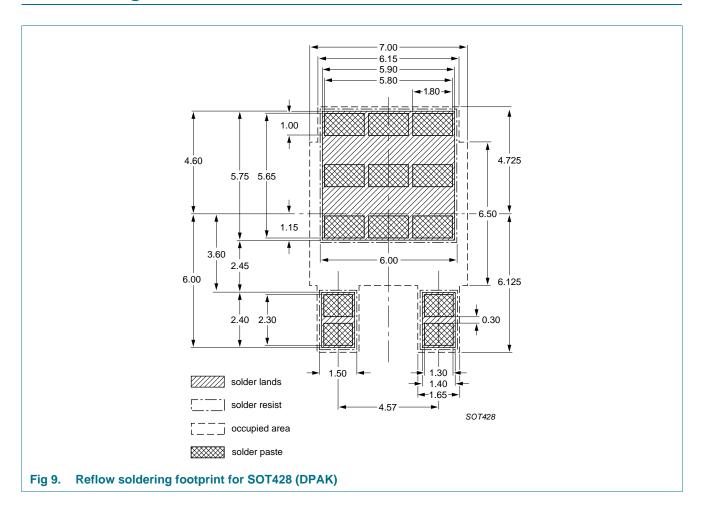


Fig 8. Package outline SOT428 (DPAK)

8. Soldering





9. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYV25FD-600 v.2	20110307	Product data sheet	-	BYV25FD-600 v.1
Modifications:	 Various chang 	es to content.		
BYV25FD-600 v.1	20101001	Product data sheet	-	-

10. Legal information

10.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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BYV25FD-600

Enhanced ultrafast power diode

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